

Fluxgate system / Voltage-output type

F23PxxxS05R SERIES



RoHS

ABSOLUTE MAXIMUM RATINGS

Parameters	Symbol	Unit	Value	Comment
Supply voltage	V _{CC}	V	7	
Primary conductor temperature	—	°C	110	
ESD (HBM: Human Body Model)	—	kV	4	C=150pF, R=330 Ω

ISOLATION CHARACTERISTICS

Parameters	Symbol	Unit	Value	Comment
Insulation voltage	V _d	—	AC5000V, for 1minute (Sensing current 0.5mA)	Primary ⇔ Secondary
Insulation Resistance	R _{IS}	—	≥ 500M Ω (at DC500V)	Primary ⇔ Secondary
Clearance distance	d _{Cl}	—	11.0mm (MIN)	Primary ⇔ Secondary
Creepage distance	d _{CP}	—	12.7mm (MIN)	Primary ⇔ Secondary
Case material	—	—	UL94 V-0	
Comparative Tracking Index : (CTI)	CTI	V	600	
Application example	—	—	600V, CAT III, PD2	Reinforced isolation,non uniform field according to EN62477-1 : 2012 and EN62477-1 : 2012/A11 2014, IEC61800-5-1
	—	—	1000V, CAT III, PD2	Basic isolation,non uniform field according to EN62477-1 : 2012 and EN62477-1 : 2012/A11 2014, IEC61800-5-1

ENVIRONMENTAL AND MECHANICAL CHARACTERISTICS

Parameters	Symbol	Unit	Value			Comment
			MIN	TYP	MAX	
Ambient operating temperature	T _A	°C	− 40		+ 85	
Ambient storage temperature	T _S	°C	− 40		+ 85	
Mass	m	g		13		

SPECIFICATIONS

Ta=+25°C, Np=1T, RL=10kΩ, Vcc=+5V

Parameters		Symbol	Unit	Value			Comment
				MIN	TYP	MAX	
Primary nominal current	F23P050S05R	IPN	A		50		
	F23P100S05R				100		
Primary current, measuring range (at Vcc= + 5V, Ta= + 85°C)	F23P050S05R	IPM	A	− 150		+ 150	
	F23P100S05R			− 200		+ 200	
Supply Voltage		VCC	V	4.75	5.00	5.25	
Number of primary turns		Np	T	1, 2, 3			
Number of secondary turns	F23P050S05R	Ns	T		1441		
	F23P100S05R				1127		
Consumption current (at If)	F23P050S05R	Icc	mA		55		Icc=20+IPN/Ns
	F23P100S05R				110		
Reference voltage (output) (at IP=0A)		Vref1	V	2.495	2.500	2.505	Ref OUT mode
Reference voltage (input)		Vref2	V	0		4	Ref IN mode
Output voltage (at Ip=0A)		Vo	V		Vref1, Vref2		
Electrical offset voltage * 1	F23P050S05R	Voe	mV	− 2.5		2.5	
	F23P100S05R						
Electrical offset current referred to primary	F23P050S05R	Ioe	mA	− 200		200	
	F23P100S05R			− 400		400	
Temperature coefficient of Vref1		TCVref1	ppm/K		± 5.0	± 50	
Temperature coefficient of Output voltage (at Ip=0A)	F23P050S05R	TCVo	ppm/K		± 3.0	± 10	ppm/K of 2.5V (− 40°C~+ 85°C)
	F23P100S05R						
Theoretical sensitivity	F23P050S05R	Gth	mV/A		12.5		625mV (at IPN) = Vref - Vout / IPN
	F23P100S05R				6.25		
Sensitivity error		εG	%	− 0.7		0.7	
Temperature coefficient of Sensitivity (at Ta= − 40°C~+ 85°C)		TCG	ppm/K			± 40	
Linearity error (at IP)		εL	%	− 0.1		0.1	
External recommended resistance of Vout		RL	kΩ		10		
External recommended capacitance of Vout		CL	pF			500	

*1 Offset voltage value is after removal of core hysteresis.

SPECIFICATIONS

Ta=+25°C, Np=1T, RL=10kΩ, Vcc=+5V

Parameters	Symbol	Unit	Value			Comment
			MIN	TYP	MAX	
Peak to peak output ripple at oscillator frequency (f typ =450kHz)	—	mV		5	20	RL=1kΩ
Reaction time (at 10% of IPN)	F23P050S05R F23P100S05R	t _{ra}			0.5	RL=1kΩ, di/dt=100A/μs
Response time (at 90% of IPN)	F23P050S05R F23P100S05R	tr			0.5	RL=1kΩ, di/dt=100A/μs
Frequency bandwidth (±3dB)	BW	kHz		100		RL=1kΩ
Output Voltage Accuracy (Overall)	F23P050S05R F23P100S05R	X _G			1.2	X _G = (100 × V _{oe} /625) + ε _G + ε _L

STANDARDS

EN62477-1 : 2012 and EN62477-1 : 2012/A11 2014, EN(IEC)61800-5-1, UL508 (file No. E243511), CSA22.2 No.14-13

※ Please refer to the another sheet about conditions of UL Recognition.

Characteristic curve (TYP)

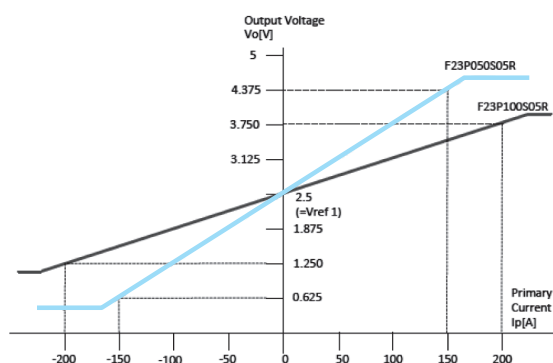


Figure 1 : Linearity curve (Internal reference voltage)
Measurement condition Ta=+25°C, RL=10kΩ, Vcc=+5V

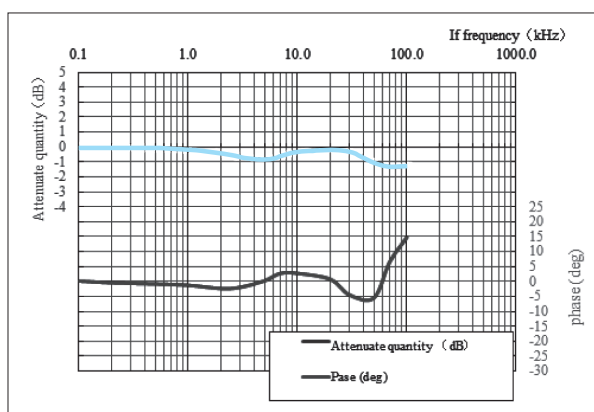


Figure 2 : Frequency response curve
ex) F23P100S05R
Measurement condition Ta=+25°C, RL=1kΩ, Ip=3A × 3T, Vcc=+5V

SUPPORT DOCUMENTATION

Maximum continuous DC primary current

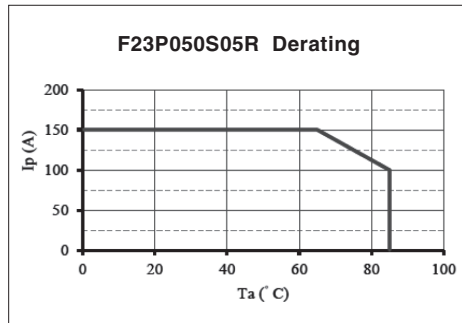


Figure 3 : Ip vs Ta for F23P050S05R

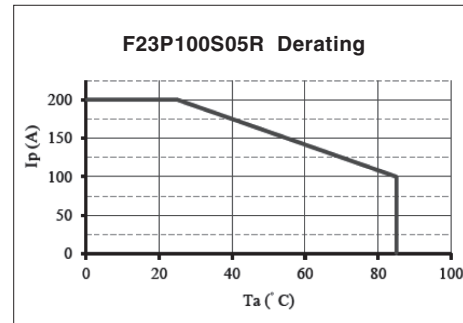


Figure 4 : Ip vs Ta for F23P100S05R

Measurement condition Vcc=+5V, RL=10kΩ

According to which the following conditions are true the maximum continuous DC primary current plot shows the boundary of the area.

- ① $I_p < I_{pmax}$
- ② Junction temperature $T_j < 125^{\circ}\text{C}$
- ③ Resistor power dissipation $< 0.5 \times \text{rated power}$

Frequency derating

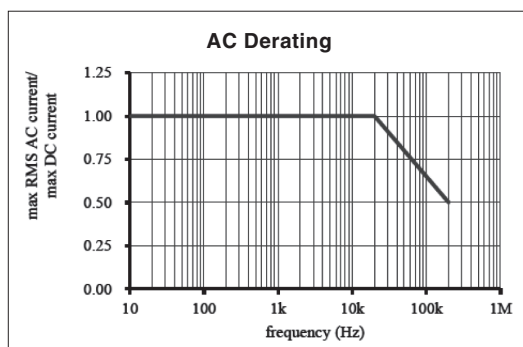


Figure 7 : Maximum RMS AC primary current/maximum DC primary current vs frequency

Reference voltage

The Ref pin has two modes Ref IN and Ref OUT :

< Ref OUT mode >

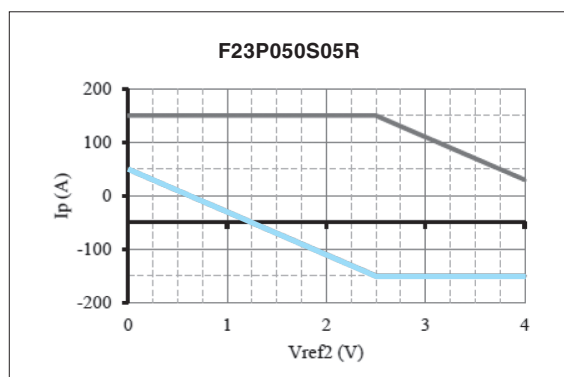
The 2.5V internal precision reference is used by the transducer as the reference point for bipolar measurements;

< Ref IN mode >

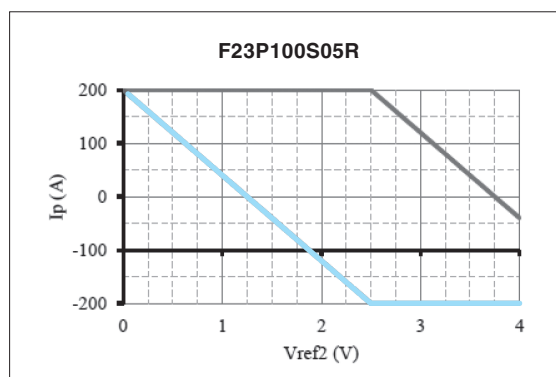
An external reference voltage is connected to the Ref pin; this voltage is specified in the range 0 to 4 V , its voltage is used as the reference voltage at the time of measurement.

- either to source a typical current of $(V_{ref} - 2.5) / 680$, the maximum value will be 2.2mA typ. when $V_{ref2} = 4V$.
- or to sink a typical current of $(2.5 - V_{ref2}) / 680$, the maximum value will be 3.68mA typ. when $V_{ref2} = 0V$.

The following graphs show how the measuring range of each transducer version depends on external reference voltage value V_{ref2} .



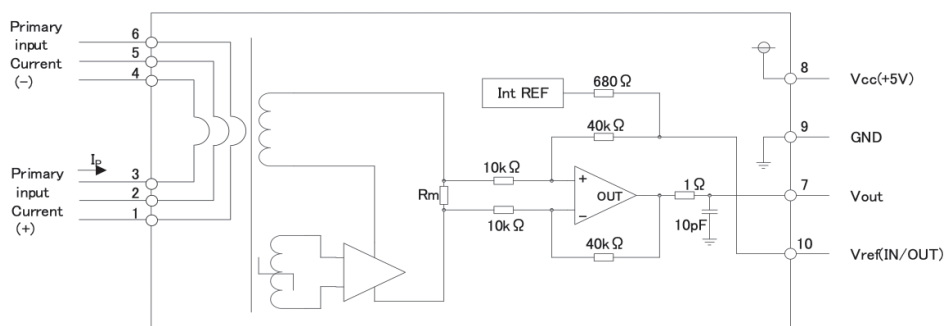
Upper limit : $I_p = 150$ ($V_{ref2} = 0 \dots 2.5V$)
 $I_p = -80 \times V_{ref2} + 350$ ($V_{ref2} = 2.5 \dots 4V$)
 Lower limit : $I_p = -80 \times V_{ref2} + 50$ ($V_{ref2} = 0 \dots 2.5V$)
 $I_p = -150$ ($V_{ref2} = 2.5 \dots 4V$)



Upper limit : $I_p = 200$ ($V_{ref2} = 0 \dots 2.5V$)
 $I_p = -160 \times V_{ref2} + 600$ ($V_{ref2} = 2.5 \dots 4V$)
 Lower limit : $I_p = -160 \times V_{ref2} + 200$ ($V_{ref2} = 0 \dots 2.5V$)
 $I_p = -200$ ($V_{ref2} = 2.5 \dots 4V$)

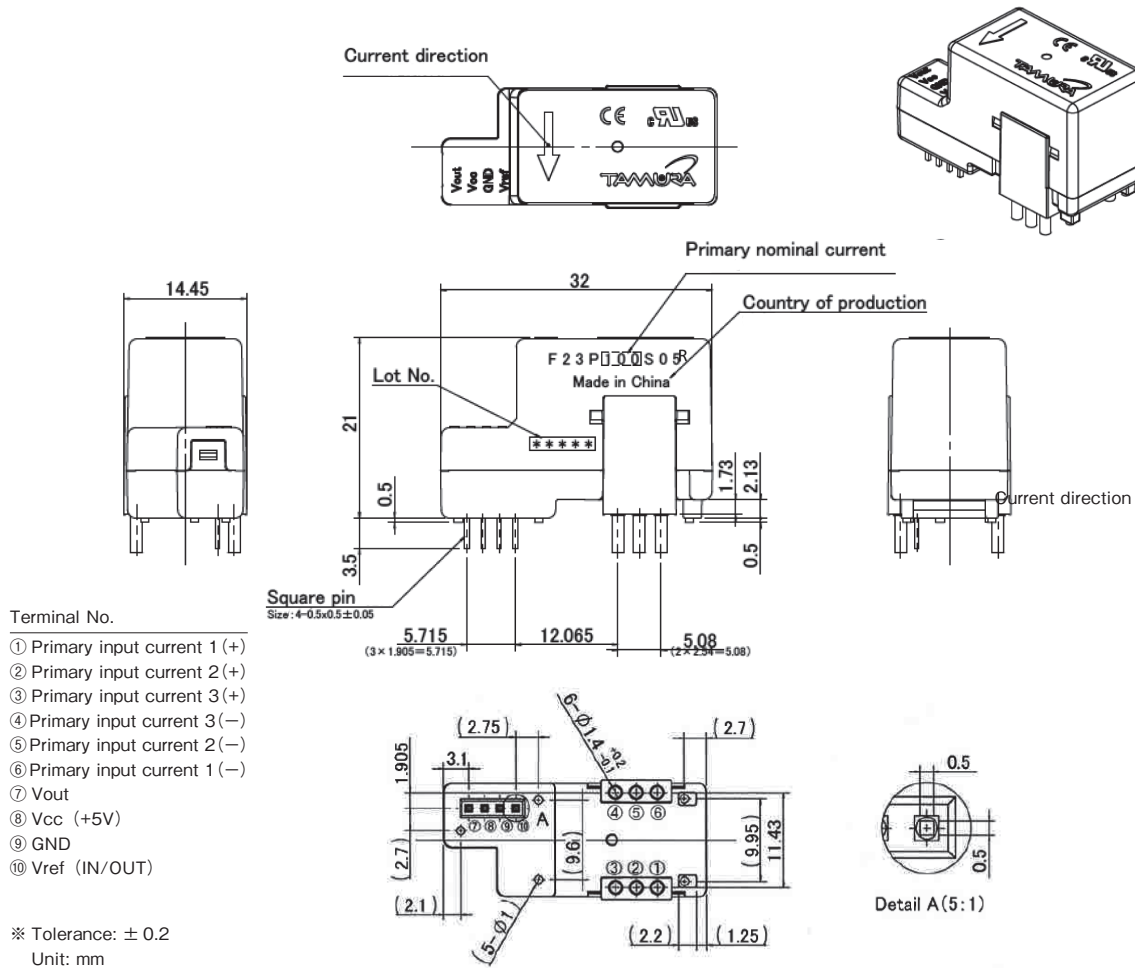
If you do not want to use the Ref pin, please unconnected.

CONNECTION



Primary winding I_p	Primary current I_p (A)	wiring	Primary resistance R_p (mΩ)
3	$I_p/3$		1
2	$I_p/2$		0.45
1	I_p		0.1

DIMENSIONS (mm)



RECOMMENDED HOLE DIAMETER (mm)

